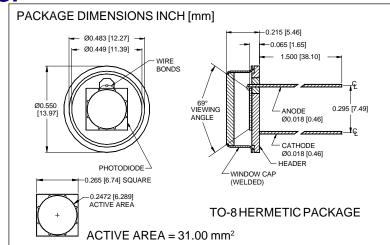
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive DETECTORS INC. Type PDB-C108





FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The **PDB-C108** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-8 metal can with a flat window.

APPLICATIONS

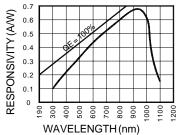
- Instrumentation
- Industrial controls
- Photoelectric switches
- Flame sensors

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		100	V
T _{STG}	Storage Temperature	-55	+150	∘C
To	Operating Temperature Range	-40	+125	∘C
Ts	Soldering Temperature*		+240	°C
IL	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

		(= 0 0 0				
SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	400	460		μΑ
ΙD	Dark Current	$H = 0$, $V_R = 10 V$		5	15	nA
Rsн	Shunt Resistance	$H = 0$, $V_R = 10 \text{ mV}$	65	120		MΩ
TC RsH	RsH Temp. Coefficient	$H = 0$, $V_R = 10 \text{ mV}$		-8		%/℃
Cı	Junction Capacitance	H = 0, V _R = 10 V**		75		pF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
V _{BR}	Breakdown Voltage	I = 10 μA	100	125		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		8x10 ⁻¹³		W/ √Hz
tr	Response Time	RL = 1 KΩ V _R = 50 V		20		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. **f = 1 MHz